

### Fast switching diode chip in Emitter Controlled -Technology

#### Features:

- 1700V technology, Emitter Controlled
- soft, fast switching
- low reverse recovery charge
- small temperature coefficient

#### This chip is used for:

 power modules and discrete devices



#### **Applications:**

• SMPS, resonant applications, drives

Chip Type	<b>V</b> <sub>R</sub>	<b>I</b> F	Die Size	Package
SIDC73 D170E6	1700V	100A	8.53 x 8.53 mm <sup>2</sup>	sawn on foil

Mechanical Parameter					
Raster size	8.53 x 8.53				
Area total	72.76	$mm^2$			
Anode pad size	6.51 x 6.51				
Thickness	200	μm			
Wafer size	150	mm			
Max. possible chips per wafer	189				
Passivation frontside	Photoimide				
Pad metal	3200 nm AlSiCu				
Backside metal	Ni Ag –system suitable for epoxy and soft solder die bonding				
Die bond	Electrically conductive glue or solder				
Wire bond	AI, ≤500μm				
Reject ink dot size	Ø 0.65mm; max 1.2mm				
Recommended storage environment	Store in original container, in dry nitrogen, in dark environment, < 6 month at an ambient temperature of 23°C				



#### **Maximum Ratings**

Parameter	Symbol	Condition	Value	Unit	
Repetitive peak reverse voltage	$V_{RRM}$	<i>T</i> <sub>vj</sub> = 25 °C	1700	V	
Continuous forward current	I <sub>F</sub>	<i>T</i> <sub>vj</sub> < 150°C	1)		
Maximum repetitive forward current	I <sub>FRM</sub>	<i>T</i> <sub>vj</sub> < 150°C	200	- A	
Junction temperature range	$T_{\rm vj}$		-40+175	°C	
Operating junction temperature	$T_{\rm vj}$		-40+150	°C	
Dynamic ruggedness <sup>2)</sup>	P <sub>max</sub>	$I_{\text{Fmax}} = 200\text{A}, \ V_{\text{Rmax}} = 1700\text{V}$ $T_{\text{vj}} \le 150^{\circ}\text{C}$	tbd	kW	

<sup>1)</sup> depending on thermal properties of assembly

### Static Characteristic (tested on wafer), $T_{vj}$ = 25 °C

Parameter	Symbol	Conditions	Value			Unit
			min.	typ.	max.	Oiiit
Reverse leakage current	$I_{R}$	V <sub>R</sub> =1700V			27	μΑ
Cathode - Anode breakdown Voltage	$V_{BR}$	I <sub>R</sub> =4m A	1700			V
Diode forward voltage	$V_{F}$	I <sub>F</sub> =100A		2.15		V

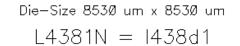
#### **Further Electrical Characteristic**

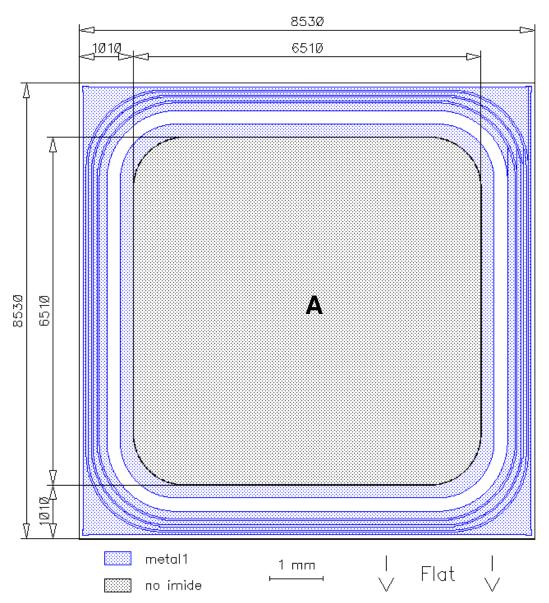
Switching characteristics and thermal properties are depending strongly on module design and mounting technology and can therefore not be specified for a bare die.

<sup>&</sup>lt;sup>2)</sup> not subject to production test - verified by design/characterisation



### **Chip Drawing**





A: Anode pad



#### Description

AQL 0.65 for visual inspection according to failure catalogue

Electrostatic Discharge Sensitive Device according to MIL-STD 883

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